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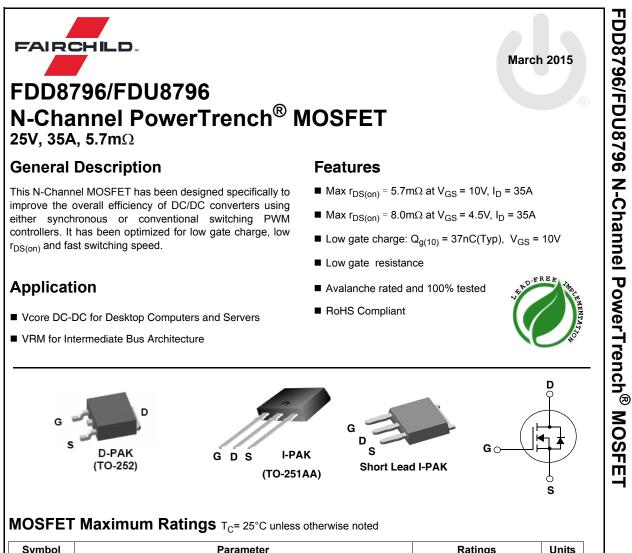


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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Symbol	Parameter		Ratings	Units	
V _{DS}	Drain to Source Voltage		25	V	
V _{GS}	Gate to Source Voltage		±20	V	
ID	Drain Current -Continuous (Package Limited) -Continuous (Die Limited)		35		
			98	Α	
	-Pulsed (N	ote 1)	305		
E _{AS}	Single Pulse Avalanche Energy (N	ote 2)	91	mJ	
PD	Power Dissipation		88	W	
T _J , T _{STG}	Operating and Storage Temperature		-55 to 175	°C	
Fhermal	Characteristics				
$R_{\theta JC}$	Thermal Resistance, Junction to Case TO_252, TO_251		1.7	°C/W	

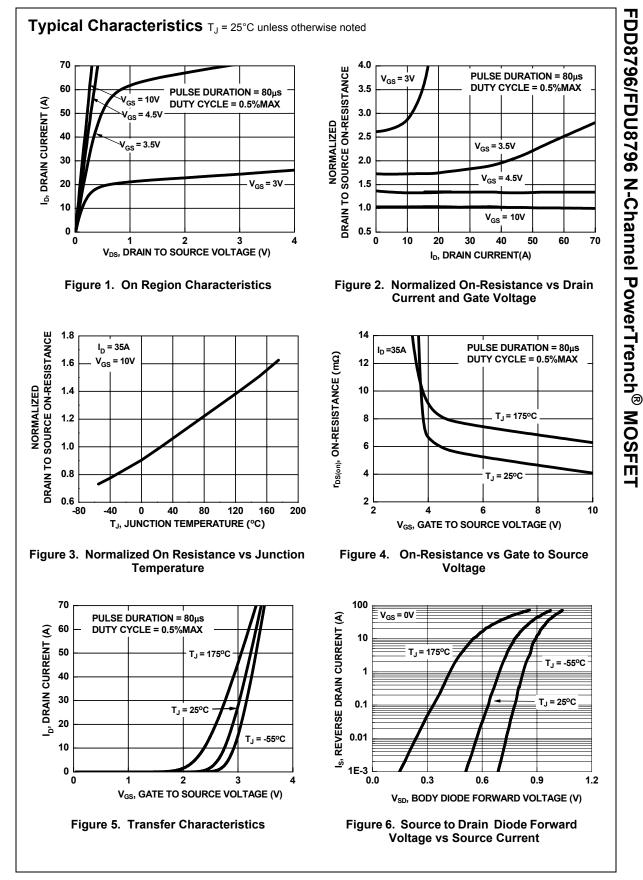
R_{\thetaJC}	Thermal Resistance, Junction to Case TO_252, TO_251	1.7	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient TO_252, TO_251	100	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient TO-252,1in ² copper pad area	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8796	FDD8796	TO-252AA	13"	16mm	2500 units
FDU8796	FDU8796	TO-251AA	N/A (Tube)	N/A	75 units
FDU8796	FDU8796_F071	TO-251AA	N/A (Tube)	N/A	75 units

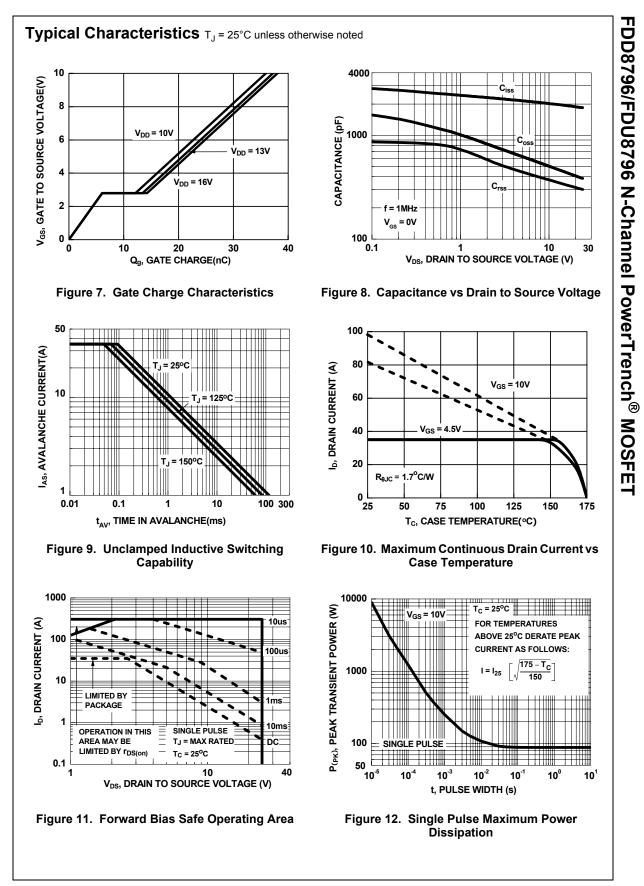
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	25			V	
ΔB _{VDSS} ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to $25^{\circ}C$		7		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 20V$ $V_{GS} = 0V$ $T_{J} = 150^{\circ}C$			1 250	μA	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$			±100	nA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1.2	1.8	2.5	V	
$\Delta V_{GS(th)}$ ΔT_J	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to $25^{\circ}C$		-6.7		mV/°C	
·		V _{GS} = 10V, I _D = 35A		4.5	5.7		
r _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V, I _D = 35A		6.0	8.0	mΩ	
		V _{DS} = 10V, I _D = 35A T _J = 175°C		6.9	9.5	11122	
Dynamic	Characteristics						
C _{iss}	Input Capacitance			1960	2610	pF	
C _{oss}	Output Capacitance	— V _{DS} = 13V, V _{GS} = 0V, — f = 1MHz		455	605	pF	
C _{rss}	Reverse Transfer Capacitance			315	475	pF	
R _G	Gate Resistance	f = 1MHz		1.1		Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			10	20	ns	
t _r	Rise Time	V _{DD} =13V, I _D = 35A		24	39	ns	
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 20\Omega$		99	158	ns	
t _f	Fall Time			57	91	ns	
Qg	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{GS} = 0 \text{ to } 5V$ $V_{DD} = 13V,$ $I_{D} = 35A,$		37	52	nC	
Q _g	Total Gate Charge	$V_{GS} = 0 \text{ to } 5V$ $V_{DD} = 13V,$		19	27	nC	
Q _{gs}	Gate to Source Gate Charge	I _D = 35A, I _a = 1.0mA		6		nC	
Q _{gd}	Gate to Drain Charge	ig itemation		6		nC	
Drain-Sou	urce Diode Characteristics	- · · · ·					
V _{SD}	Source to Drain Diade Valtage	V _{GS} = 0V, I _S = 35A		0.9	1.25	V	
	Source to Drain Diode Voltage	V _{GS} = 0V, I _S = 15A		0.8	1.0	V	
t _{rr}	Reverse Recovery Time	I _F = 35A, di/dt = 100A/μs		30	45	ns	
Q _{rr}	Reverse Recovery Charge	I _F = 35A, di/dt = 100A/μs		23	35	nC	

 $\label{eq:relation} \begin{array}{|c|c|c|} \hline Q_{fT} & Reverse Recovery ordered \\ \hline $Notes:$ \\ 1: Pulse time < 300 \mu s, Duty cycle = 2%. \\ 2: Starting T_J = 25^\circ C, L = 0.3mH, I_{AS} = 24.7A, V_{DD} = 23V, V_{GS} = 10V. \\ \hline \end{tabular}$

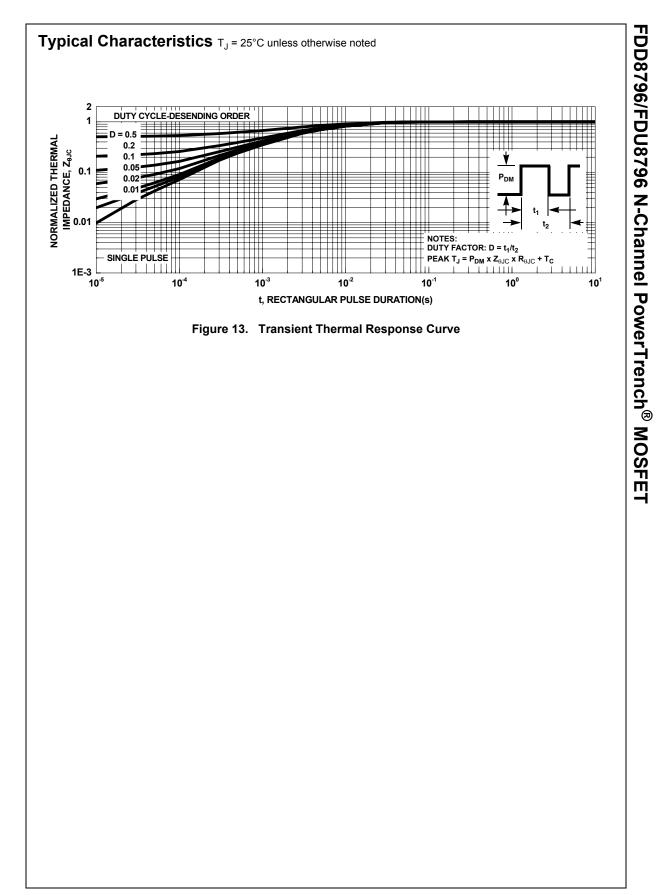


FDD8796/FDU8796 Rev. 1.1

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